

N- and P-Channel 30V (D-S) Power MOSFET

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

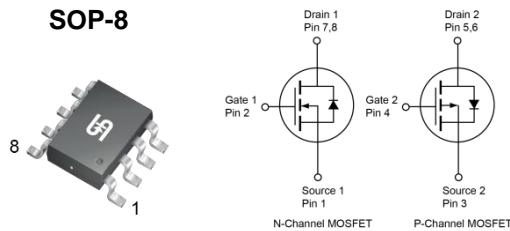
- DC-DC Converters
- Power Routing
- Motor Drives

KEY PERFORMANCE PARAMETERS			
PARAMETER	TYPE	VALUE	UNIT
V_{DS}	N-ch	30	V
	P-ch	-30	
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	16	$m\Omega$
	$V_{GS} = 4.5V$	20	
	$V_{GS} = -10V$	24	$m\Omega$
	$V_{GS} = -4.5V$	37	
Q_g	N-ch	7	nC
	P-ch	11	



✓
RoHS
COMPLIANT

HALOGEN
FREE



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	N-ch	P-ch	UNIT
Drain-Source Voltage	V_{DS}	30	-30	V
Gate-Source Voltage	V_{GS}	± 20	± 25	V
Continuous Drain Current ^(Note 1)	I_D	15	13	A
$T_C = 25^\circ C$		8	7	
Pulsed Drain Current	I_{DM}	60	52	A
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	12	18	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	21.6	48.6	mJ
Total Power Dissipation	P_D	6	6	W
$T_C = 125^\circ C$		1.2	1.2	
Total Power Dissipation	P_D	1.6	1.6	W
$T_A = 25^\circ C$		0.3	0.3	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150		°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance – Junction to Case	$R_{\Theta JC}$	21	°C/W
Thermal Resistance – Junction to Ambient	$R_{\Theta JA}$	78	

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)								
PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT	
Static								
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu\text{A}$	BV_{DSS}	N-ch	30	--	--	V	
	$V_{GS} = 0V, I_D = -250\mu\text{A}$		P-ch	-30	--	--		
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	N-ch	1	1.4	2.5	V	
	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$		P-ch	-1	-1.7	-2.5		
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	N-ch	--	--	± 100	nA	
	$V_{GS} = \pm 25V, V_{DS} = 0V$		P-ch	--	--	± 100	nA	
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 30V$	I_{DSS}	N-ch	--	--	1	μA	
	$V_{GS} = 0V, V_{DS} = 30V$			--	--	100		
	$T_J = 125^\circ\text{C}$		P-ch	--	--	-1		
	$V_{GS} = 0V, V_{DS} = -30V$			--	--	-100		
	$V_{GS} = 0V, V_{DS} = -30V$		P-ch	--	--	$T_J = 125^\circ\text{C}$		
Drain-Source On-State Resistance ^(Note 3)	$V_{GS} = 10V, I_D = 8A$	$R_{DS(\text{on})}$	N-ch	--	10	16	$\text{m}\Omega$	
	$V_{GS} = 4.5V, I_D = 8A$			--	13	20		
	$V_{GS} = -10V, I_D = -7A$		P-ch	--	18	24		
	$V_{GS} = -4.5V, I_D = -7A$			--	30	37		
Forward Transconductance ^(Note 3)	$V_{DS} = 5V, I_D = 8A$	g_{fs}	N-ch	--	26	--	S	
	$V_{DS} = -5V, I_D = -7A$		P-ch	--	16	--		
Dynamic								
Total Gate Charge	N-ch $V_{DS} = 15V, I_D = 8A$	$Q_{g(VGS=10V)}$	N-ch	--	14	--	nC	
Total Gate Charge			P-ch	--	21.5	--		
Gate-Source Charge		$Q_{g(VGS=4.5V)}$	N-ch	--	7	--		
Gate-Drain Charge			P-ch	--	11	--		
Input Capacitance		Q_{gs}	N-ch	--	1.7	--		
Output Capacitance			P-ch	--	3.4	--		
Reverse Transfer Capacitance	$f = 1.0\text{MHz}$ $V_{GS} = 0V, V_{DS} = -15V$	Q_{gd}	N-ch	--	3.7	--	pF	
Gate Resistance			P-ch	--	5.3	--		
Input Capacitance	N-ch $V_{GS} = 0V, V_{DS} = 15V$ $f = 1.0\text{MHz}$	C_{iss}	N-ch	--	646	--	pF	
			P-ch	--	1089	--		
Output Capacitance		C_{oss}	N-ch	--	108	--		
			P-ch	--	190	--		
Reverse Transfer Capacitance		C_{rss}	N-ch	--	70	--		
			P-ch	--	119	--		
Gate Resistance	$f = 1.0\text{MHz}$	R_g	N-ch	0.9	3	6	Ω	
			P-ch	3.6	12	24		

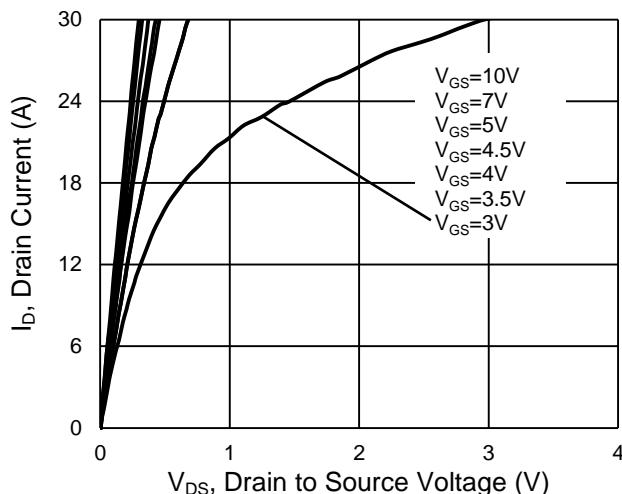
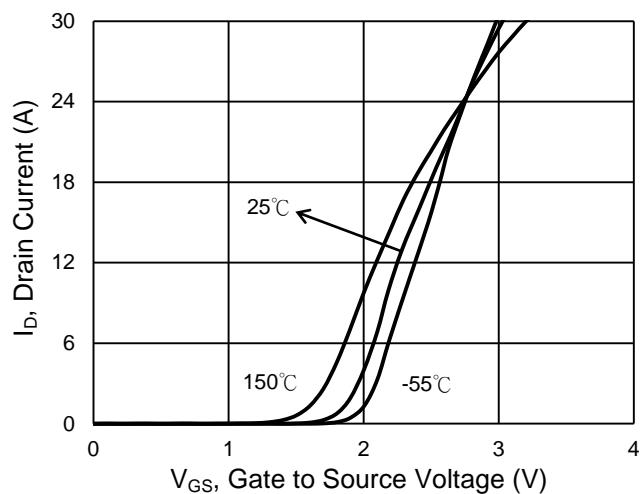
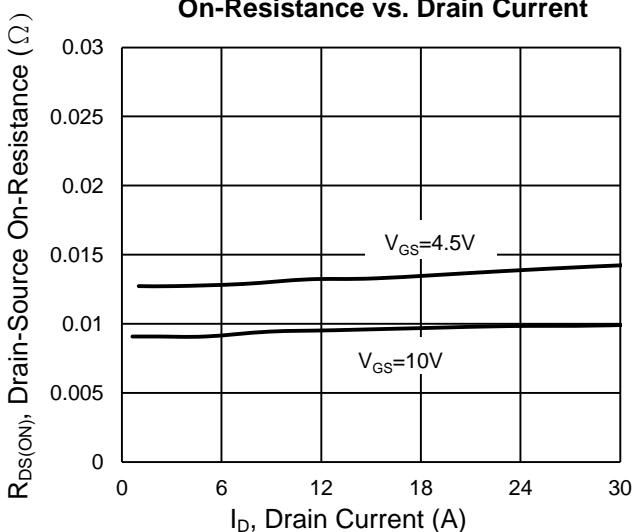
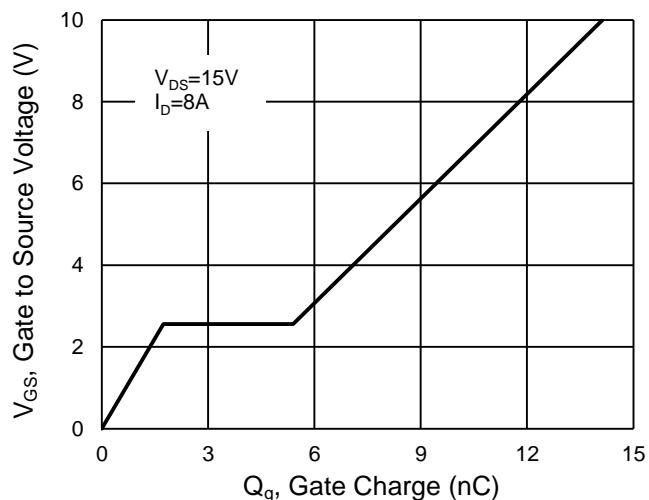
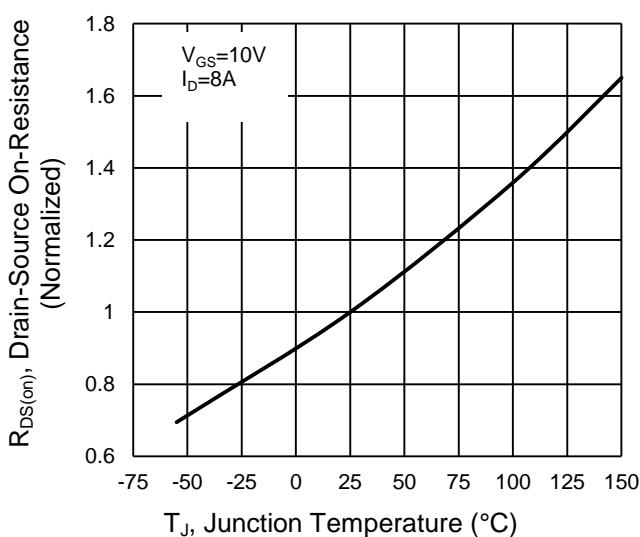
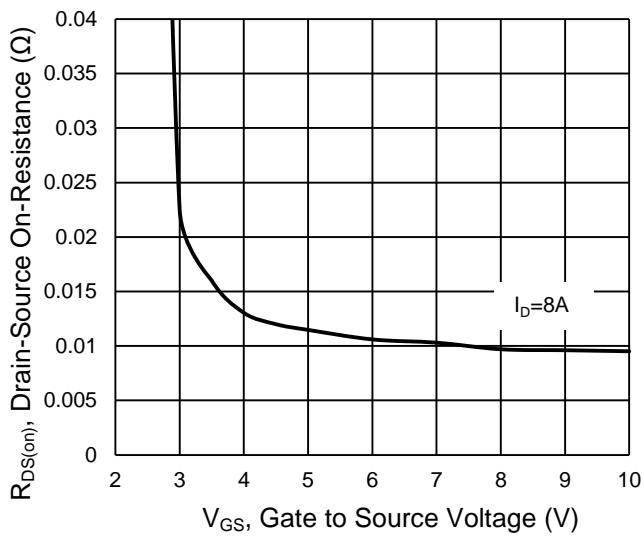
ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT
Switching <small>(Note 4)</small>							
Turn-On Delay Time	N-ch $V_{GS} = 10V, V_{DS} = 15V, I_D = 8A, R_G = 2\Omega$	$t_{d(on)}$	N-ch	--	5.4	--	ns
			P-ch	--	6.2	--	
	P-ch $V_{GS} = -10V, V_{DS} = -15V, I_D = -7A, R_G = 2\Omega$	t_r	N-ch	--	41.3	--	
			P-ch	--	40.4	--	
	Turn-Off Delay Time	$t_{d(off)}$	N-ch	--	18	--	
			P-ch	--	45.4	--	
	Turn-Off Fall Time	t_f	N-ch	--	5.6	--	
			P-ch	--	45.4	--	
Source-Drain Diode							
Forward Voltage <small>(Note 3)</small>	$V_{GS} = 0V, I_S = 8A$	V_{SD}	N-ch	--	--	1	V
	$V_{GS} = 0V, I_S = -7A$		P-ch	--	--	-1	
Reverse Recovery Time	N-ch $I_S = 8A, dI/dt = 100A/\mu\text{s}$	t_{rr}	N-ch	--	14	--	ns
			P-ch	--	32	--	
	P-ch $I_S = -7A, dI/dt = 100A/\mu\text{s}$	Q_{rr}	N-ch	--	4	--	nC
			P-ch	--	10	--	

Notes:

1. Silicon limited current only.
2. N-ch : $L = 0.3mH, V_{GS} = 10V, V_{DD} = 25V, R_G = 25\Omega, I_{AS} = 12A$, Starting $T_J = 25^\circ\text{C}$
P-ch : $L = 0.3mH, V_{GS} = 10V, V_{DD} = 25V, R_G = 25\Omega, I_{AS} = 18A$, Starting $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

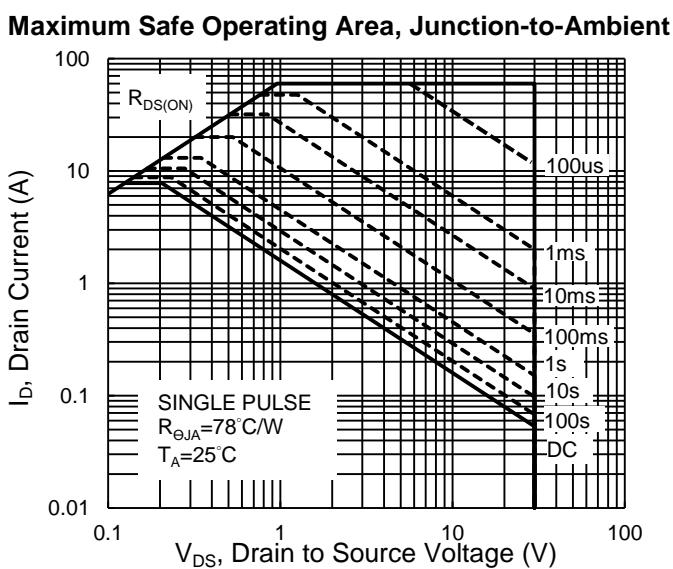
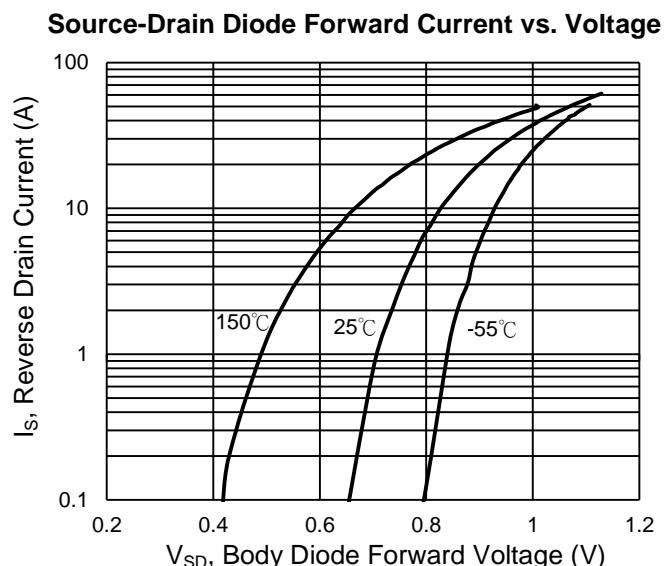
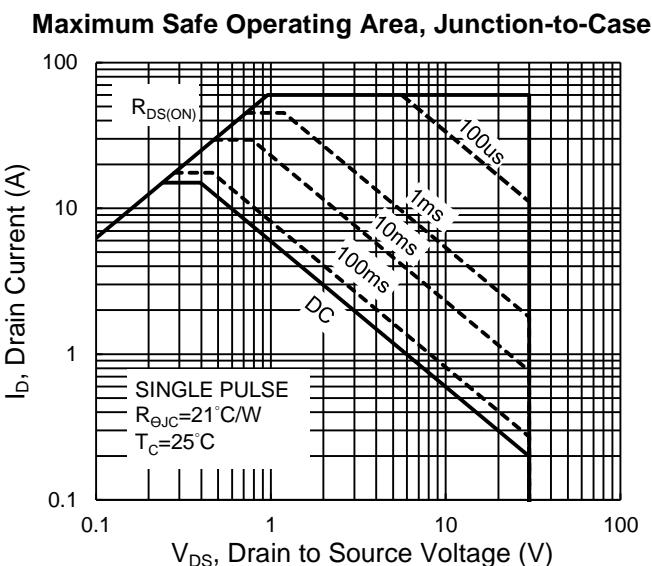
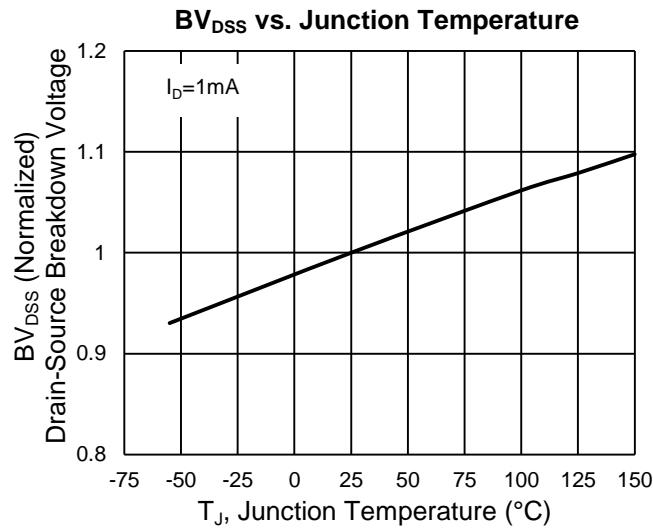
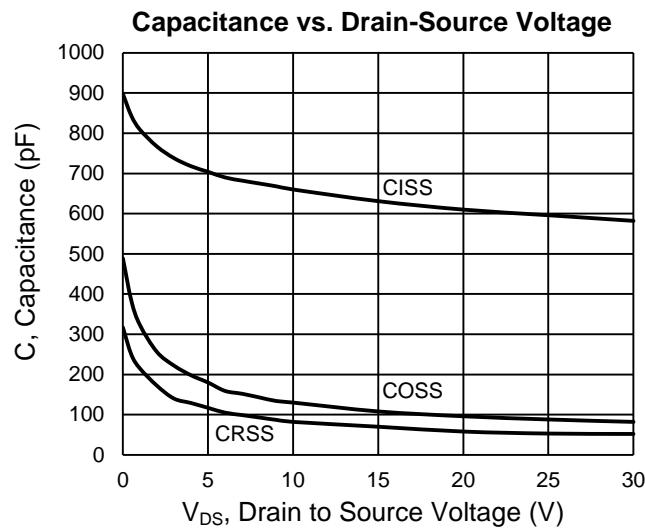
ORDERING INFORMATION

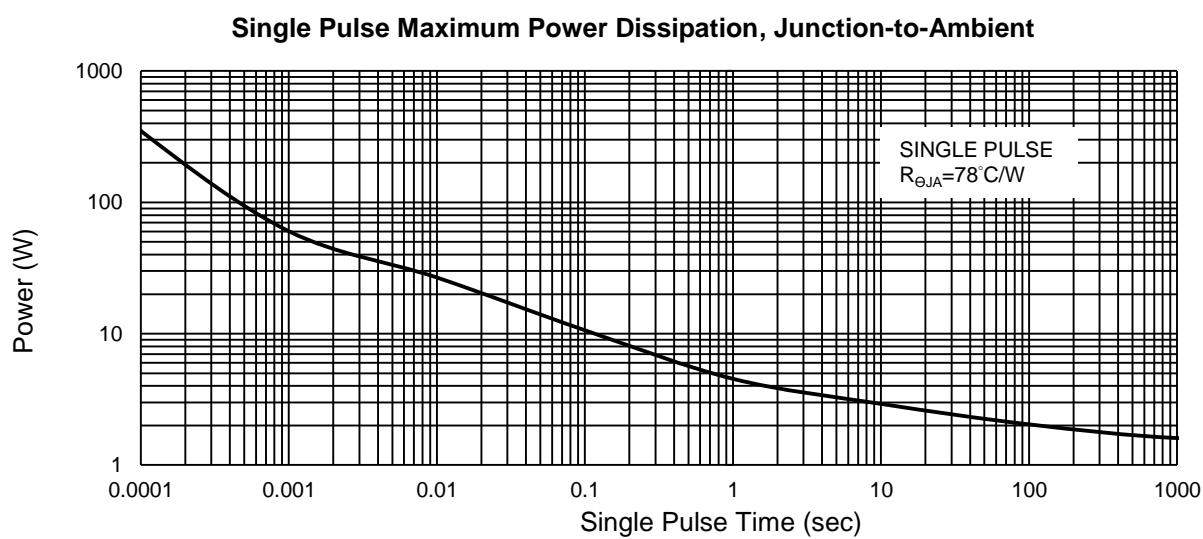
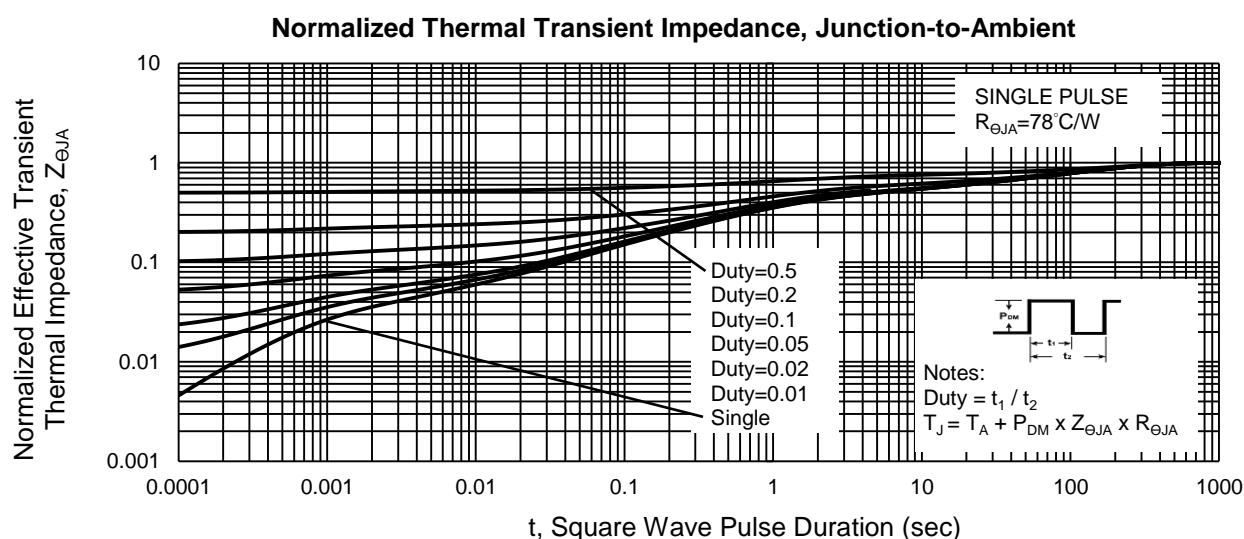
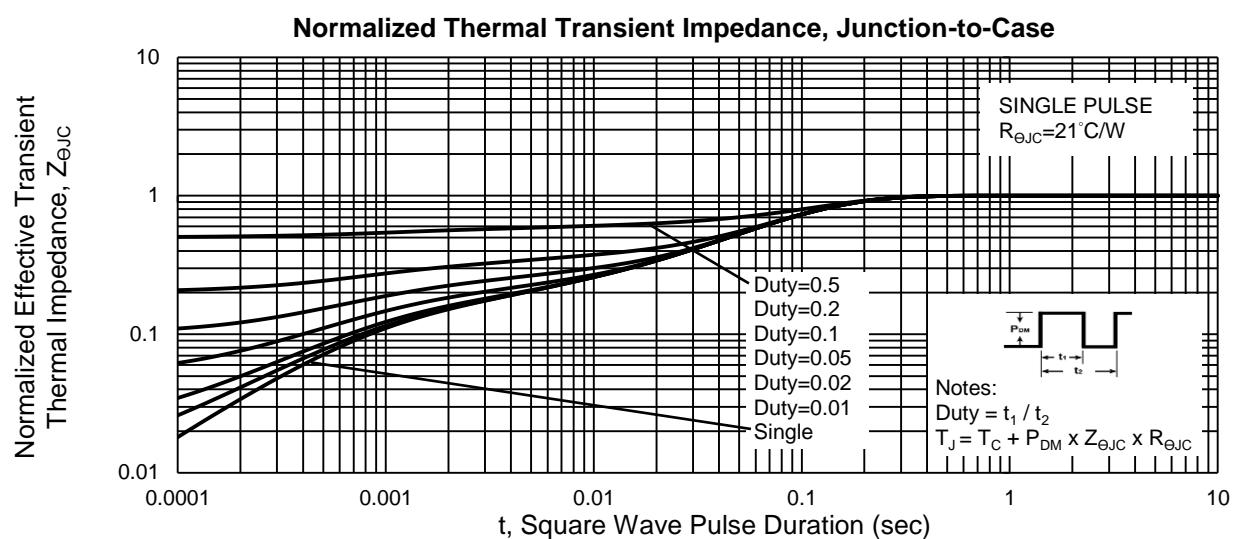
PART NO.	PACKAGE	PACKING
TSM8568CS RLG	SOP-8	2,500pcs / 13" Reel

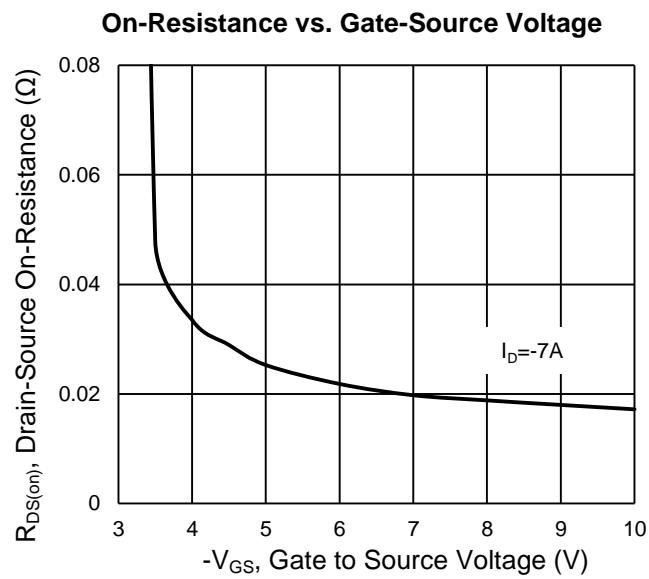
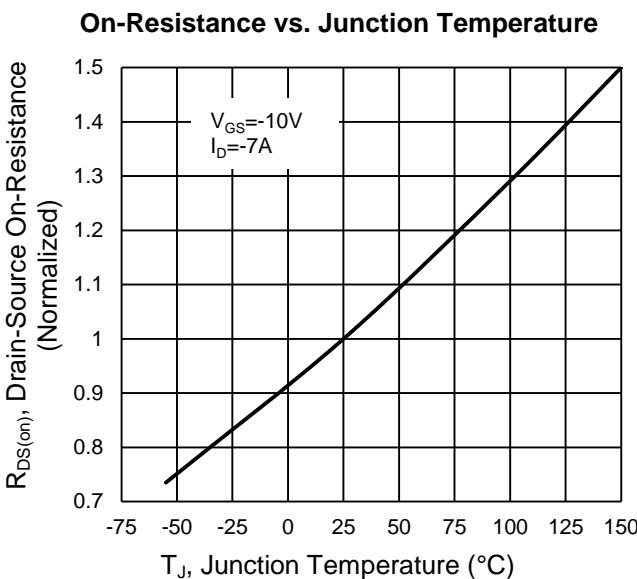
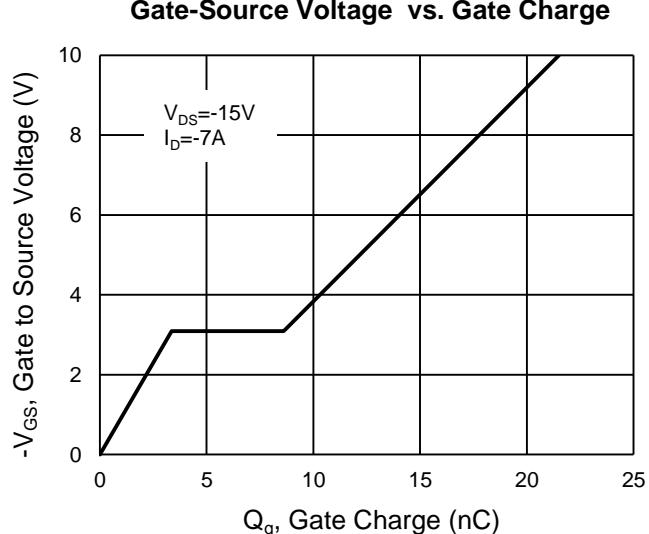
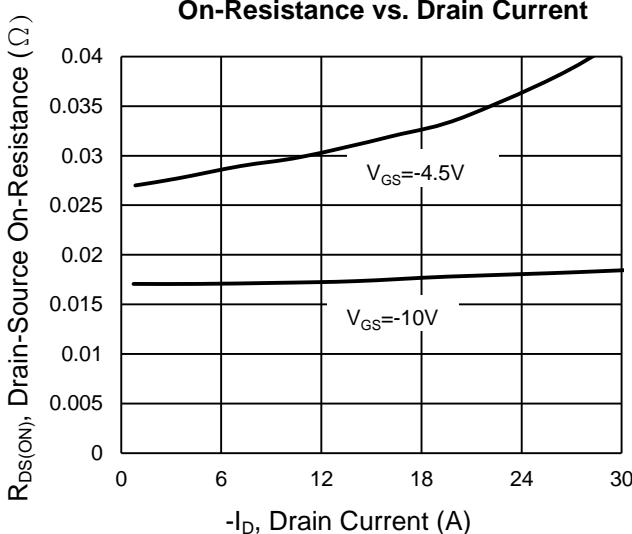
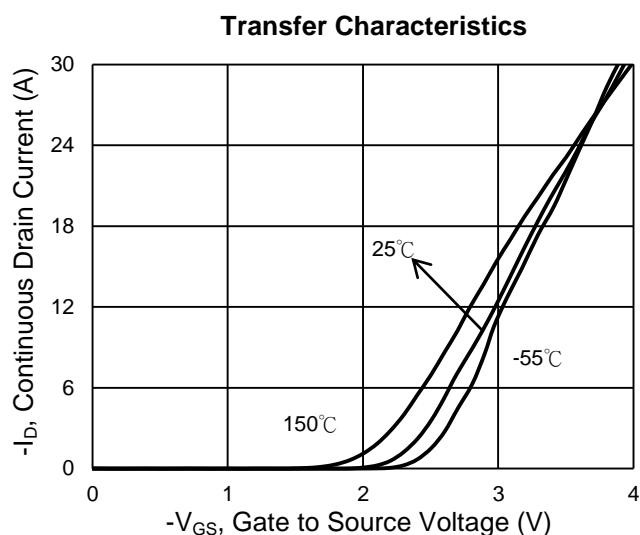
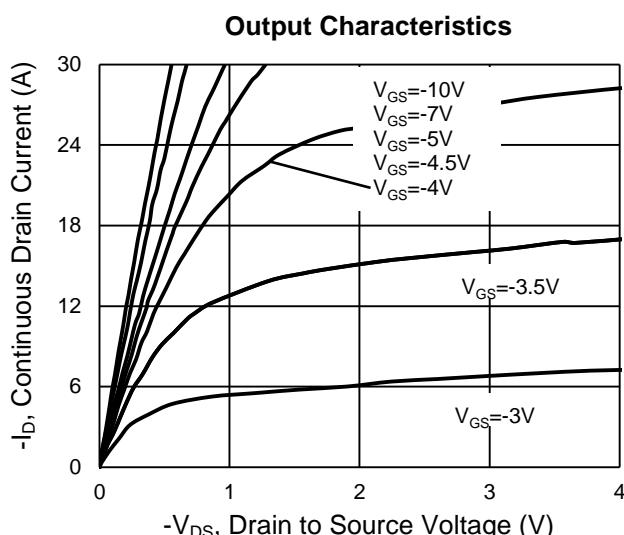
CHARACTERISTICS CURVES (N-Channel)
 $(T_A = 25^\circ\text{C} \text{ unless otherwise noted})$
Output Characteristics

Transfer Characteristics

On-Resistance vs. Drain Current

Gate-Source Voltage vs. Gate Charge

On-Resistance vs. Junction Temperature

On-Resistance vs. Gate-Source Voltage


CHARACTERISTICS CURVES (N-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)

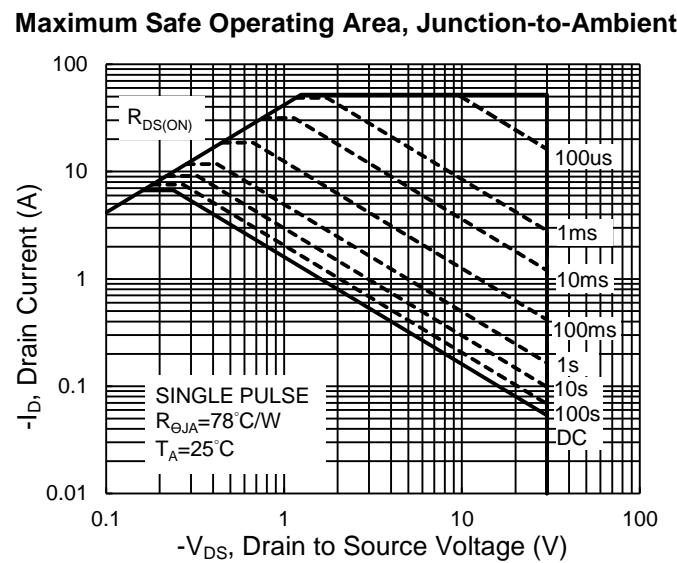
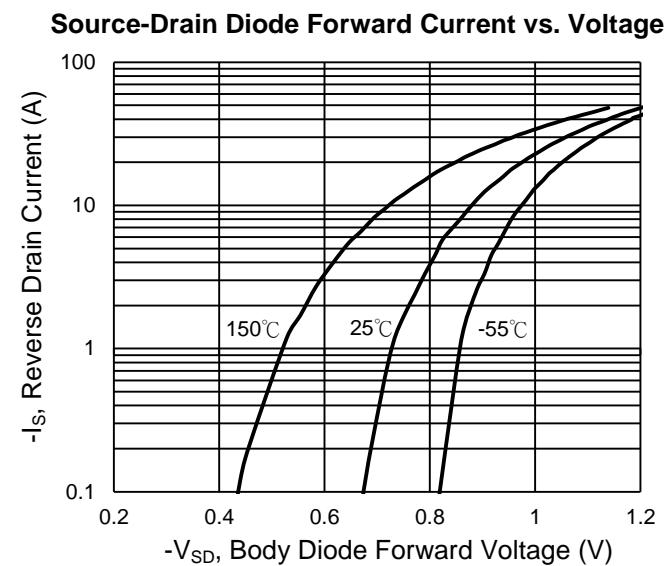
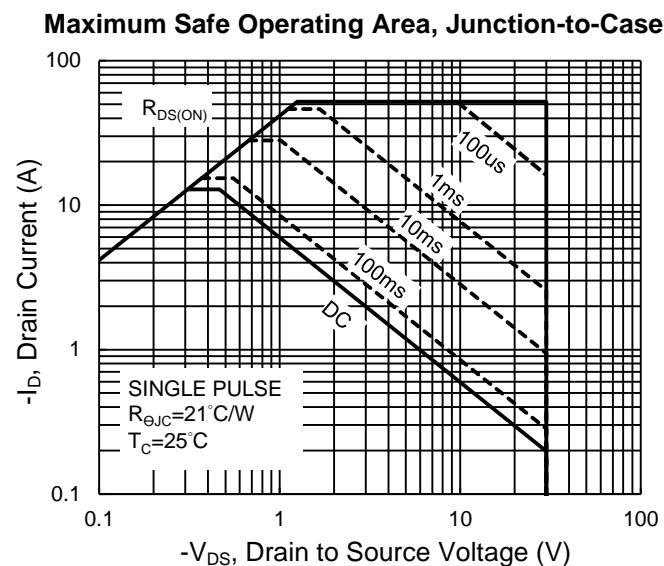
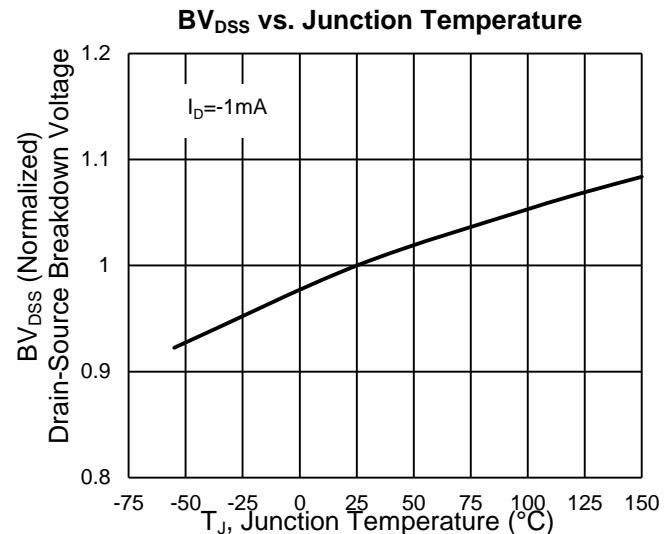
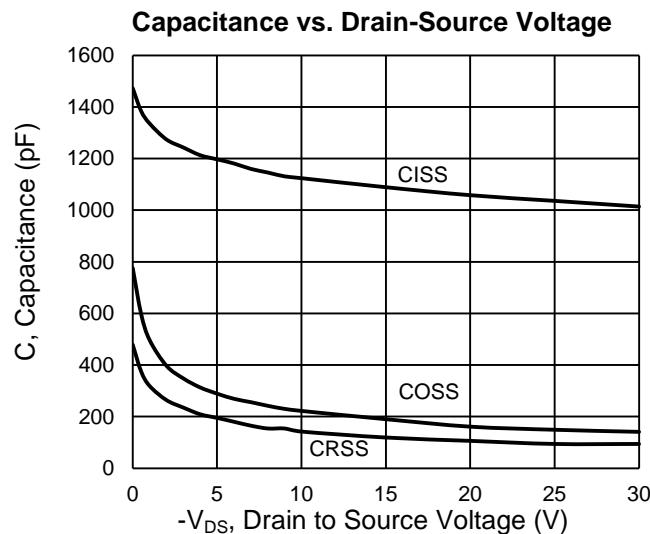


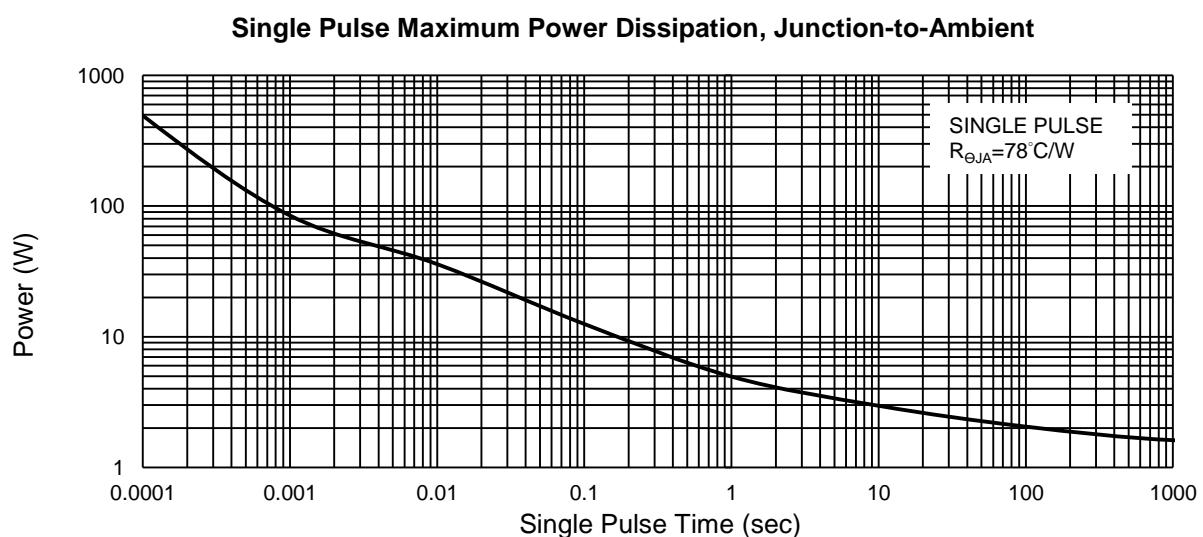
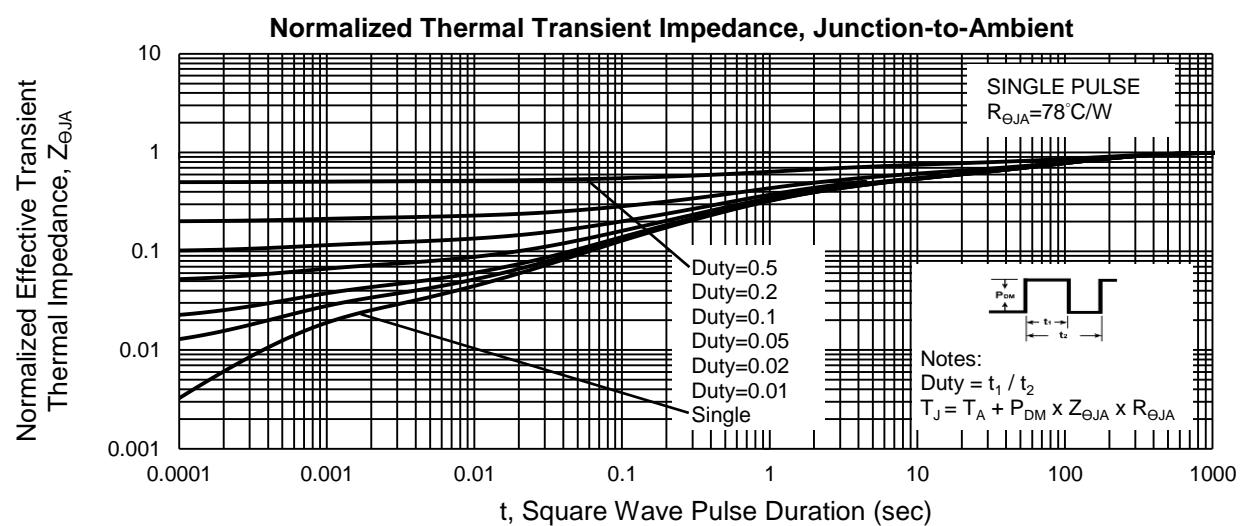
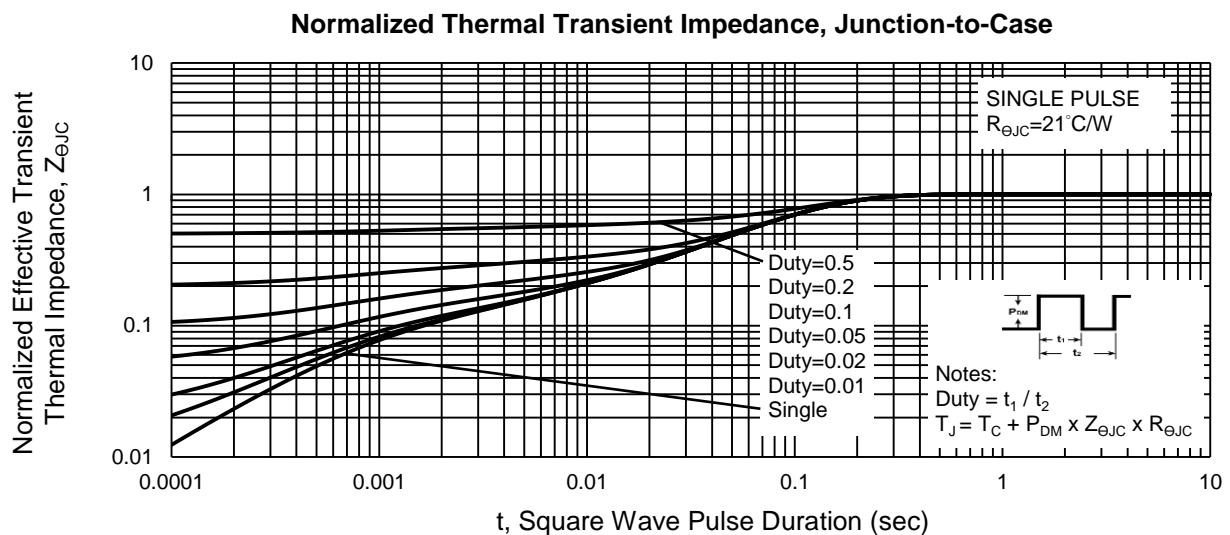


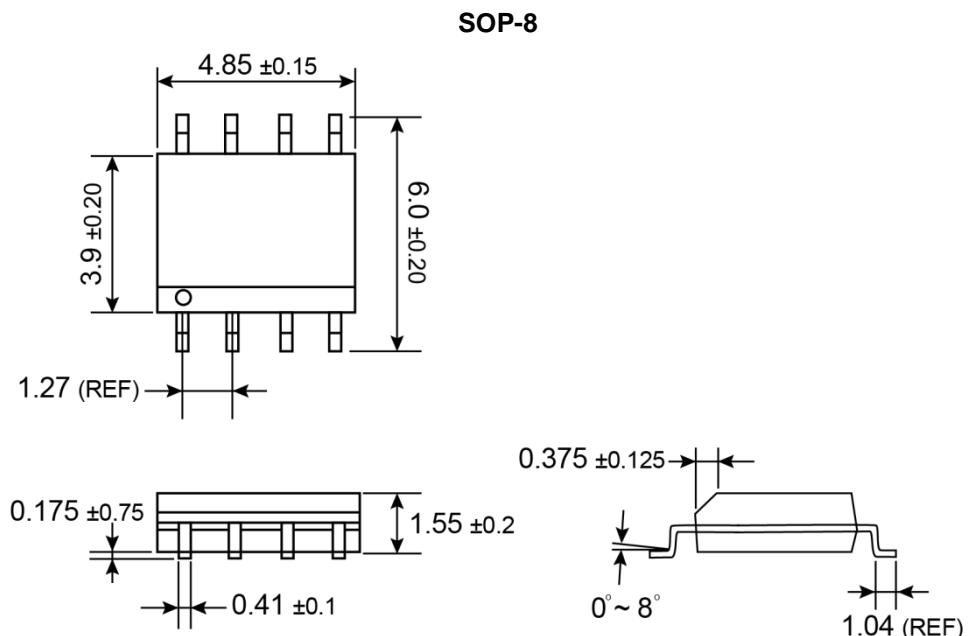
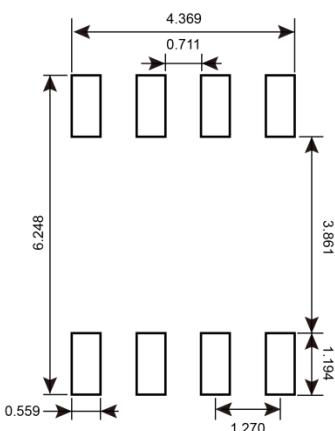
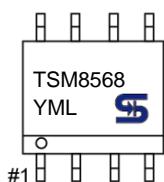
CHARACTERISTICS CURVES (P-Channel)
 $(T_A = 25^\circ\text{C} \text{ unless otherwise noted})$


CHARACTERISTICS CURVES (P-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)





PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM

Y = Year Code

M = Month Code

O =Jan **P** =Feb **Q** =Mar **R** =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep **X** =Oct **Y** =Nov **Z** =Dec

L = Lot Code (1~9, A~Z)

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